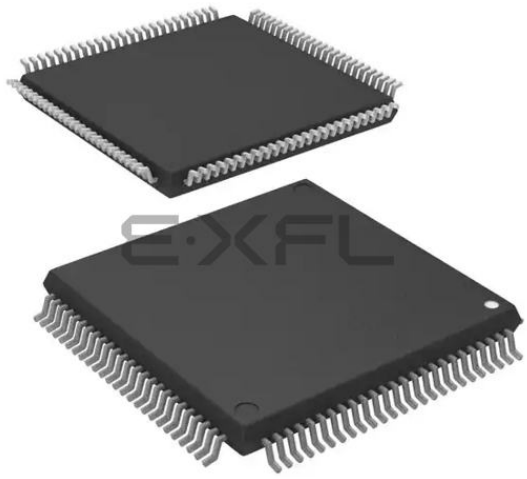
Renesas Electronics America Inc - R5F2L3AACNFP#V0 Datasheet



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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Discontinued at Digi-Key
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I²C, LINbus, SIO, SSU, UART/USART
Peripherals	LCD, POR, PWM, Voltage Detect, WDT
Number of I/O	88
Program Memory Size	96KB (96K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	10K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 20x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LFQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f2l3aacnfp-v0

Table 1.2 Programmable I/O Ports Provided for Each Group

Programmable I/O Port	R8C/L35C Group Total: 41 I/O pins								R8C/L36C Group Total: 52 I/O pins								R8C/L38C Group Total: 68 I/O pins								R8C/L3AC Group Total: 88 I/O pins							
	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0	bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
P0	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
P1	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
P2	✓	✓	✓	✓	–	–	–	–	✓	✓	✓	✓	–	–	–	–	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
P3	–	–	–	–	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
P4	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
P5	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	✓	✓	✓	✓
P6	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
P7	✓	✓	✓	✓	–	–	–	–	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
P10	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	✓	✓	✓	✓	✓	✓	✓	✓
P11	–	–	–	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
P12	–	–	–	–	✓	✓	✓	✓	–	–	–	–	✓	✓	✓	✓	–	–	–	–	✓	✓	✓	✓	–	–	–	–	✓	✓	✓	✓
P13	–	–	–	–	✓	✓	✓	✓	–	–	–	–	✓	✓	✓	✓	–	–	–	–	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓

Notes:
1. The symbol "✓" indicates a programmable I/O port.
2. The symbol "–" indicates the settings should be made as follows:
   - Set 1 to the corresponding bits in the PDi (i = 1 to 3, 5 to 7, and 10 to 13) register.
   - Set 0 to the corresponding bits in the Pi (i = 1 to 3, 5 to 7, and 10 to 13) register.
   - Set 0 to the corresponding bits in the P10DRR or P11DRR register.

Table 1.3 LCD Display Function Pins Provided for Each Group

Shared I/O Port	L35C Group Common output: Max. 4 Segment output: Max. 24								L36C Group Common output: Max. 8 Segment output: Max. 32								L38C Group Common output: Max. 8 Segment output: Max. 48								L3AC Group Common output: Max. 8 Segment output: Max. 56							
P0	SEG 7	SEG 6	SEG 5	SEG 4	SEG 3	SEG 2	SEG 1	SEG 0	SEG 7	SEG 6	SEG 5	SEG 4	SEG 3	SEG 2	SEG 1	SEG 0	SEG 7	SEG 6	SEG 5	SEG 4	SEG 3	SEG 2	SEG 1	SEG 0	SEG 7	SEG 6	SEG 5	SEG 4	SEG 3	SEG 2	SEG 1	SEG 0
P1	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	SEG 11	SEG 10	SEG 9	SEG 8	SEG 15	SEG 14	SEG 13	SEG 12	SEG 11	SEG 10	SEG 9	SEG 8
P2	SEG 23	SEG 22	SEG 21	SEG 20	–	–	–	–	SEG 23	SEG 22	SEG 21	SEG 20	–	–	–	–	SEG 23	SEG 22	SEG 21	SEG 20	SEG 19	SEG 18	SEG 17	SEG 16	SEG 23	SEG 22	SEG 21	SEG 20	SEG 19	SEG 18	SEG 17	SEG 16
P3	–	–	–	–	SEG 27	SEG 26	SEG 25	SEG 24	SEG 31	SEG 30	SEG 29	SEG 28	SEG 27	SEG 26	SEG 25	SEG 24	SEG 31	SEG 30	SEG 29	SEG 28	SEG 27	SEG 26	SEG 25	SEG 24	SEG 31	SEG 30	SEG 29	SEG 28	SEG 27	SEG 26	SEG 25	SEG 24
P4	SEG 39	SEG 38	SEG 37	SEG 36	SEG 35	SEG 34	SEG 33	SEG 32	SEG 39	SEG 38	SEG 37	SEG 36	SEG 35	SEG 34	SEG 33	SEG 32	SEG 39	SEG 38	SEG 37	SEG 36	SEG 35	SEG 34	SEG 33	SEG 32	SEG 39	SEG 38	SEG 37	SEG 36	SEG 35	SEG 34	SEG 33	SEG 32
P5	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	SEG 43	SEG 42	SEG 41	SEG 40
P6	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	–	SEG 51	SEG 50	SEG 49	SEG 48	SEG 47	SEG 46	SEG 45	SEG 44	SEG 51	SEG 50	SEG 49	SEG 48	SEG 47	SEG 46	SEG 45	SEG 44
P7	COM 0	COM 1	COM 2	COM 3	–	–	–	–	COM 0	COM 1	COM 2	COM 3	SEG 55	SEG 54	SEG 53	SEG 52	COM 0	COM 1	COM 2	COM 3	SEG 55	SEG 54	SEG 53	SEG 52	COM 0	COM 1	COM 2	COM 3	SEG 55	SEG 54	SEG 53	SEG 52
P12	–	–	–	–	CL2	CL1	–	–	–	–	–	–	CL2	CL1	–	–	–	–	–	–	CL2	CL1	–	–	–	–	–	–	CL2	CL1	–	–
–	VL1								VL1								VL1								VL1							
–	VL2								VL2								VL2								VL2							
–	–								VL3								VL3								VL3							
–	VL4								VL4								VL4								VL4							

Notes:
1. The symbol "–" indicates there is no LCD display function. Set the corresponding bits in registers LSE1 to LSE3, LSE5 to LSE7 to 0 for these pins.
2. SEG52 to SEG55 can be used as COM7 to COM4.
   The R8C/L35C Group does not have pins SEG52 to SEG55, so 1/8 duty cannot be selected.
3. The R8C/L35C Group does not have the VL3 pin, so 1/4 bias cannot be selected. When the internal voltage multiplier is used, 1/2 bias cannot also be selected.

Table 1.6 Specifications (3)

Item	Specification
Flash Memory	• Programming and erasure voltage: VCC = 2.7 to 5.5 V • Programming and erasure endurance: 10,000 times (data flash) 1,000 times (program ROM) • Program security: ROM code protect, ID code check • On-chip debug function • On-board flash rewrite function • Background operation (BGO) function
Operating Frequency/ Supply Voltage	f(XIN) = 20 MHz (VCC = 2.7 to 5.5 V) f(XIN) = 5 MHz (VCC = 1.8 to 5.5 V)
Current Consumption	Typ. 7 mA (VCC = 5.0 V, f(XIN) = 20 MHz) Typ. 3.6 mA (VCC = 3.0 V, f(XIN) = 10 MHz) Typ. 3.5 μA (VCC = 3.0 V, wait mode (f(XCIN) = 32 kHz)) Typ. 2 μA (VCC = 3.0 V, stop mode) Typ. 0.02 μA (VCC = 3.0 V, power-off mode)
Operating Ambient Temperature	-20 to 85°C (N version) -40 to 85°C (D version) (1)

Note:
1. Specify the D version if D version functions are to be used.

Table 1.8 Product List for R8C/L36C Group Current of Apr 2011

Part No.	Internal ROM Capacity		Internal RAM Capacity	Package Type	Remarks
	Program ROM	Data Flash			
R5F2L367CNFP	48 Kbytes	1 Kbyte × 4	6 Kbytes	PLQP0064KB-A	N Version
R5F2L367CNFA	48 Kbytes	1 Kbyte × 4	6 Kbytes	PLQP0064GA-A	
R5F2L368CNFP	64 Kbytes	1 Kbyte × 4	8 Kbytes	PLQP0064KB-A	
R5F2L368CNFA	64 Kbytes	1 Kbyte × 4	8 Kbytes	PLQP0064GA-A	
R5F2L36ACNFP	96 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064KB-A	
R5F2L36ACNFA	96 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064GA-A	
R5F2L36CCNFP	128 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064KB-A	
R5F2L36CCNFA	128 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064GA-A	
R5F2L367CDFP	48 Kbytes	1 Kbyte × 4	6 Kbytes	PLQP0064KB-A	D Version
R5F2L367CDFA	48 Kbytes	1 Kbyte × 4	6 Kbytes	PLQP0064GA-A	
R5F2L368CDFP	64 Kbytes	1 Kbyte × 4	8 Kbytes	PLQP0064KB-A	
R5F2L368CDFA	64 Kbytes	1 Kbyte × 4	8 Kbytes	PLQP0064GA-A	
R5F2L36ACDFP	96 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064KB-A	
R5F2L36ACDFA	96 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064GA-A	
R5F2L36CCDFP	128 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064KB-A	
R5F2L36CCDFA	128 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064GA-A	

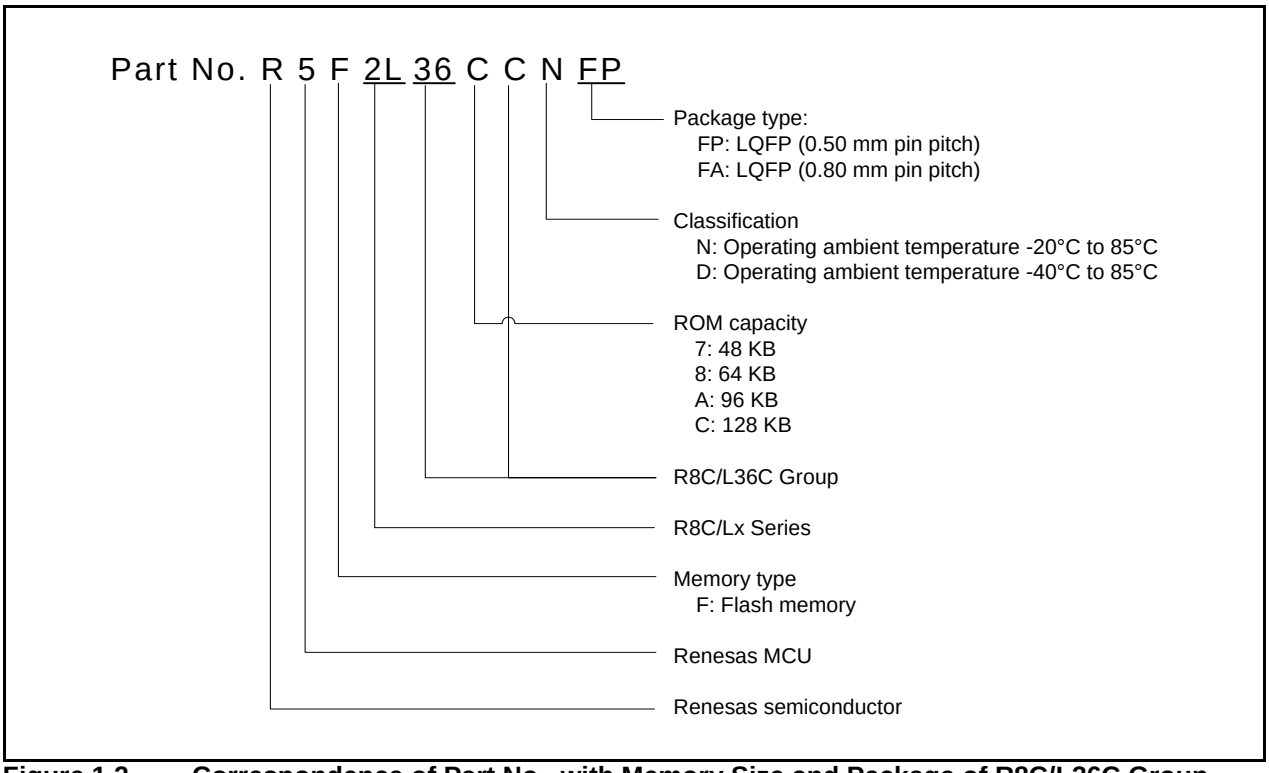
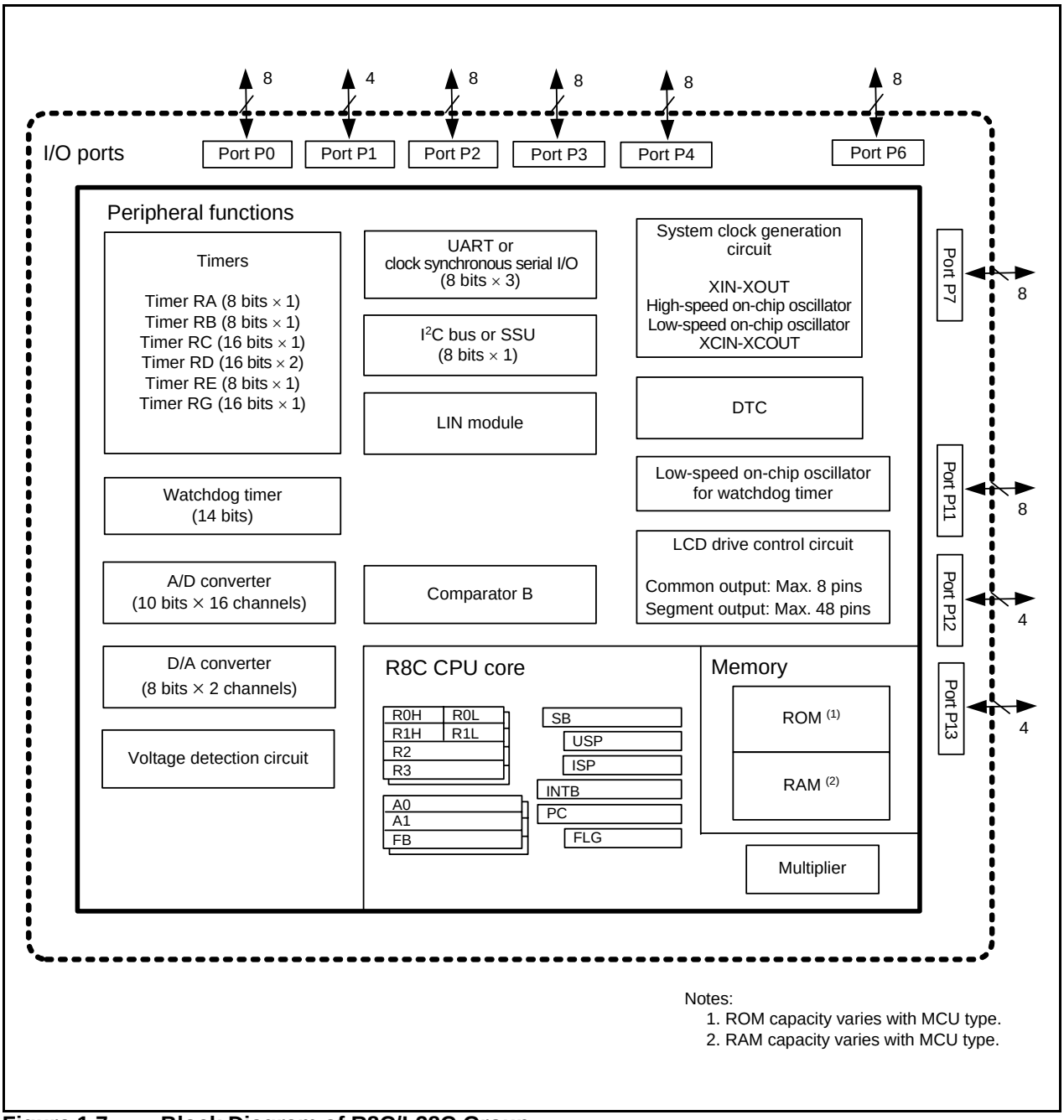
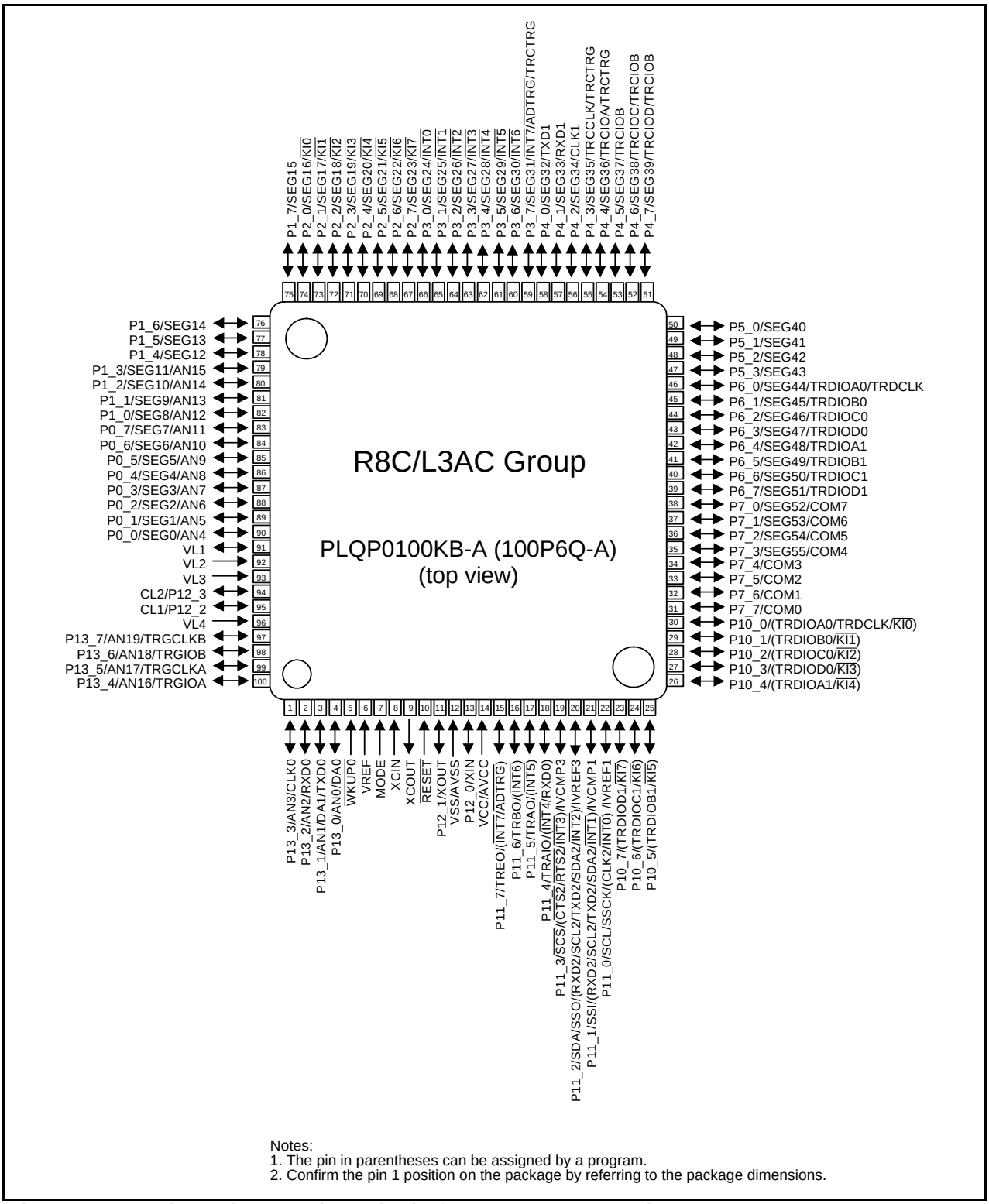


Figure 1.2 Correspondence of Part No., with Memory Size and Package of R8C/L36C Group



Notes:
1. ROM capacity varies with MCU type.
2. RAM capacity varies with MCU type.

Figure 1.7 Block Diagram of R8C/L38C Group



Notes:
1. The pin in parentheses can be assigned by a program.
2. Confirm the pin 1 position on the package by referring to the package dimensions.

Figure 1.12 Pin Assignment (Top View) of PLQP0100KB-A Package

Table 1.11 Pin Name Information by Pin Number (1)

Pin Number				Control Pin	Port	I/O Pin Functions for Peripheral Modules						
L3AC (Note 2)	L38C	L36C	L35C			Interrupt	Timer	Serial Interface	SSU	I²C bus	A/D Converter, D/A Converter, Comparator B	LCD drive control circuit
1 [3]	80	61	51		P13_3			CLK0			AN3	
2 [4]	1	62	52		P13_2			RXD0			AN2	
3 [5]	2	63	1		P13_1			TXD0			AN1/DA1	
4 [6]	3	64	2		P13_0						AN0/DA0	
5 [7]	4	1	3	$\overline{\text{WKUP0}}$								
6 [8]	5	2	4	VREF								
7 [9]	6	3	5	MODE								
8 [10]	7	4	6	XCIN								
9 [11]	8	5	7	XCOUT								
10 [12]	9	6	8	$\overline{\text{RESET}}$								
11 [13]	10	7	9	XOUT	P12_1							
12 [14]	11	8	10	VSS/ AVSS								
13 [15]	12	9	11	XIN	P12_0							
14 [16]	13	10	12	VCC/ AVCC								
15 [17]	14	11			P11_7	($\overline{\text{INT7}}$)	TREO				($\overline{\text{ADTRG}}$)	
16 [18]	15	12			P11_6	($\overline{\text{INT6}}$)	TRBO					
17 [19]	16	13			P11_5	($\overline{\text{INT5}}$)	TRAO					
18 [20]	17	14	13		P11_4	($\overline{\text{INT4}}$)	TRAIO	(RXD0)				
19 [21]	18	15	14		P11_3	($\overline{\text{INT3}}$)		($\overline{\text{CTS2}}$/$\overline{\text{RTS2}}$)	$\overline{\text{SCS}}$		IVCMP3	
20 [22]	19	16	15		P11_2	($\overline{\text{INT2}}$)		(RXD2/SCL2/ TXD2/SDA2)	SSO	SDA	IVREF3	
21 [23]	20	17	16		P11_1	($\overline{\text{INT1}}$)		(RXD2/SCL2/ TXD2/SDA2)	SSI		IVCMP1	
22 [24]	21	18	17		P11_0	($\overline{\text{INT0}}$)		(CLK2)	SSCK	SCL	IVREF1	
23 [25]					P10_7	($\overline{\text{KI7}}$)	(TRDIOD1)					
24 [26]					P10_6	($\overline{\text{KI6}}$)	(TRDIOC1)					
25 [27]					P10_5	($\overline{\text{KI5}}$)	(TRDIOB1)					
26 [28]					P10_4	($\overline{\text{KI4}}$)	(TRDIOA1)					
27 [29]					P10_3	($\overline{\text{KI3}}$)	(TRDIOD0)					
28 [30]					P10_2	($\overline{\text{KI2}}$)	(TRDIOC0)					
29 [31]					P10_1	($\overline{\text{KI1}}$)	(TRDIOB0)					
30 [32]					P10_0	($\overline{\text{KI0}}$)	(TRDIOA0/ TRDCLK)					
31 [33]	22	19	18		P7_7							COM0
32 [34]	23	20	19		P7_6							COM1
33 [35]	24	21	20		P7_5							COM2
34 [36]	25	22	21		P7_4							COM3
35 [37]	26	23			P7_3							SEG55/ COM4
36 [38]	27	24			P7_2							SEG54/ COM5
37 [39]	28	25			P7_1							SEG53/ COM6
38 [40]	29	26			P7_0							SEG52/ COM7
39 [41]	30				P6_7		TRDIOD1					SEG51

Notes:
1. The pin in parentheses can be assigned by a program.
2. The number in brackets indicates the pin number for the 100P6F package.

2.8.7 Interrupt Enable Flag (I)

The I flag enables maskable interrupts.
Interrupts are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1.
The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7.
If a requested interrupt has higher priority than IPL, the interrupt is enabled.

2.8.10 Reserved Bit

If necessary, set to 0. When read, the content is undefined.

Table 4.2 SFR Information (2) (1)

Address	Register	Symbol	After Reset
003Ah	Voltage Monitor 2 Circuit Control Register	VW2C	10000010b
003Bh			
003Ch			
003Dh			
003Eh			
003Fh			
0040h			
0041h	Flash Memory Ready Interrupt Control Register	FMRDYIC	XXXXX000b
0042h			
0043h	INT7 Interrupt Control Register	INT7IC	XX00X000b
0044h	INT6 Interrupt Control Register	INT6IC	XX00X000b
0045h	INT5 Interrupt Control Register	INT5IC	XX00X000b
0046h	INT4 Interrupt Control Register	INT4IC	XX00X000b
0047h	Timer RC Interrupt Control Register	TRCIC	XXXXX000b
0048h	Timer RD0 Interrupt Control Register	TRD0IC	XXXXX000b
0049h	Timer RD1 Interrupt Control Register	TRD1IC	XXXXX000b
004Ah	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004Bh	UART2 Transmit Interrupt Control Register	S2TIC	XXXXX000b
004Ch	UART2 Receive Interrupt Control Register	S2RIC	XXXXX000b
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Eh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
004Fh	SSU Interrupt Control Register / IIC bus Interrupt Control Register (2)	SSUIC/IICIC	XXXXX000b
0050h			
0051h	UART0 Transmit Interrupt Control Register	S0TIC	XXXXX000b
0052h	UART0 Receive Interrupt Control Register	S0RIC	XXXXX000b
0053h	UART1 Transmit Interrupt Control Register	S1TIC	XXXXX000b
0054h	UART1 Receive Interrupt Control Register	S1RIC	XXXXX000b
0055h	INT2 Interrupt Control Register	INT2IC	XX00X000b
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh			
005Ch			
005Dh	INT0 Interrupt Control Register	INT0IC	XX00X000b
005Eh	UART2 Bus Collision Detection Interrupt Control Register	U2BCNIC	XXXXX000b
005Fh			
0060h			
0061h			
0062h			
0063h			
0064h			
0065h			
0066h			
0067h			
0068h			
0069h			
006Ah			
006Bh	Timer RG Interrupt Control Register	TRGIC	XXXXX000b
006Ch			
006Dh			
006Eh			
006Fh			
0070h			
0071h			
0072h	Voltage monitor 1 Interrupt Control Register	VCMP1IC	XXXXX000b
0073h	Voltage monitor 2 Interrupt Control Register	VCMP2IC	XXXXX000b
0074h			
0075h			
0076h			
0077h			
0078h			
0079h			
007Ah			
007Bh			
007Ch			
007Dh			
007Eh			
007Fh			

X: Undefined

Notes:
1. Blank spaces are reserved. No access is allowed.
2. Selectable by the IICSEL bit in the SSUIICSR register.

Table 4.13 SFR Information (13) (1)

Address	Register	Symbol	After Reset
2C00h	DTC Transfer Vector Area		XXh
2C01h	DTC Transfer Vector Area		XXh
2C02h	DTC Transfer Vector Area		XXh
2C03h	DTC Transfer Vector Area		XXh
2C04h	DTC Transfer Vector Area		XXh
2C05h	DTC Transfer Vector Area		XXh
2C06h	DTC Transfer Vector Area		XXh
2C07h	DTC Transfer Vector Area		XXh
2C08h	DTC Transfer Vector Area		XXh
2C09h	DTC Transfer Vector Area		XXh
2C0Ah	DTC Transfer Vector Area		XXh
:	DTC Transfer Vector Area		XXh
:	DTC Transfer Vector Area		XXh
2C3Ah	DTC Transfer Vector Area		XXh
2C3Bh	DTC Transfer Vector Area		XXh
2C3Ch	DTC Transfer Vector Area		XXh
2C3Dh	DTC Transfer Vector Area		XXh
2C3Eh	DTC Transfer Vector Area		XXh
2C3Fh	DTC Transfer Vector Area		XXh
2C40h	DTC Control Data 0	DTCD0	XXh
2C41h			XXh
2C42h			XXh
2C43h			XXh
2C44h			XXh
2C45h			XXh
2C46h			XXh
2C47h			XXh
2C48h	DTC Control Data 1	DTCD1	XXh
2C49h			XXh
2C4Ah			XXh
2C4Bh			XXh
2C4Ch			XXh
2C4Dh			XXh
2C4Eh			XXh
2C4Fh			XXh
2C50h	DTC Control Data 2	DTCD2	XXh
2C51h			XXh
2C52h			XXh
2C53h			XXh
2C54h			XXh
2C55h			XXh
2C56h			XXh
2C57h			XXh
2C58h	DTC Control Data 3	DTCD3	XXh
2C59h			XXh
2C5Ah			XXh
2C5Bh			XXh
2C5Ch			XXh
2C5Dh			XXh
2C5Eh			XXh
2C5Fh			XXh
2C60h	DTC Control Data 4	DTCD4	XXh
2C61h			XXh
2C62h			XXh
2C63h			XXh
2C64h			XXh
2C65h			XXh
2C66h			XXh
2C67h			XXh
2C68h	DTC Control Data 5	DTCD5	XXh
2C69h			XXh
2C6Ah			XXh
2C6Bh			XXh
2C6Ch			XXh
2C6Dh			XXh
2C6Eh			XXh
2C6Fh			XXh

X: Undefined
Note:
1. Blank spaces are reserved. No access is allowed.

5. Electrical Characteristics

5.1 Absolute Maximum Ratings

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter		Condition	Rated Value	Unit
V_{CC}/AV_{CC}	Supply voltage			–0.3 to 6.5	V
V_I	Input voltage	XIN	XIN-XOUT oscillation on (oscillation buffer ON) (1)	–0.3 to 1.65	V
		XIN	XIN-XOUT oscillation on (oscillation buffer OFF) (1)	–0.3 to V_{CC} + 0.3	V
		VL1		–0.3 to VL2	V
		VL2	R8C/L35C	VL1 to VL4	V
			R8C/L36C, R8C/L38C, R8C/L3AC	VL1 to VL3	V
		VL3		VL2 to VL4	V
		VL4		VL3 to 6.5	V
		Other pins		–0.3 to V_{CC} + 0.3	V
V_O	Output voltage	XOUT	XIN-XOUT oscillation on (oscillation buffer ON) (1)	–0.3 to 1.65	V
		XOUT	XIN-XOUT oscillation on (oscillation buffer OFF) (1)	–0.3 to V_{CC} + 0.3	V
		VL1		–0.3 to VL2 (2)	V
		VL2	R8C/L35C	VL1 to VL4	V
			R8C/L36C, R8C/L38C, R8C/L3AC	VL1 to VL3	V
		VL3		VL2 to VL4	V
		VL4		–0.3 to 6.5	V
		CL1, CL2		–0.3 to 6.5	V
		COM0 to COM7		–0.3 to VL4	V
		SEG0 to SEG55		–0.3 to VL4	V
		Other pins		–0.3 to V_{CC} + 0.3	V
P_d	Power dissipation		–40°C ≤ T_{opr} ≤ 85°C	500	mW
T_{opr}	Operating ambient temperature			–20 to 85 (N version) / –40 to 85 (D version)	°C
T_{stg}	Storage temperature			–65 to 150	°C

Notes:
1. For the register settings for each operation, refer to **7. I/O Ports** and **9. Clock Generation Circuit** in the User's Manual: Hardware.
2. The VL1 voltage should be VCC or below.

Table 5.6 Flash Memory (Program ROM) Characteristics
(V_{CC} = 2.7 to 5.5 V and T_{opr} = 0 to 60°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
—	Program/erase endurance (1)		1,000 (2)	—	—	times
—	Byte program time		—	80	500	µs
—	Block erase time		—	0.3	—	s
$t_{d(SR-SUS)}$	Time delay from suspend request until suspend		—	—	5 + CPU clock × 3 cycles	ms
—	Interval from erase start/restart until following suspend request		0	—	—	ms
—	Time from suspend until erase restart		—	—	30+CPU clock × 1 cycle	µs
$t_{d(CMDRST-READY)}$	Time from when command is forcibly terminated until reading is enabled		—	—	30+CPU clock × 1 cycle	µs
—	Program, erase voltage		2.7	—	5.5	V
—	Read voltage		1.8	—	5.5	V
—	Program, erase temperature		0	—	60	°C
—	Data hold time (6)	Ambient temperature = 55°C	20	—	—	year

Notes:
1. Definition of programming/erasure endurance
   The programming and erasure endurance is defined on a per-block basis.
   If the programming and erasure endurance is n (n = 1,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.
   However, the same address must not be programmed more than once per erase operation (overwriting prohibited).
2. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
3. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.
4. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
5. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
6. The data hold time includes time that the power supply is off or the clock is not supplied.

Table 5.7 Flash Memory (Data flash Block A to Block D) Characteristics (V_{CC} = 2.7 to 5.5 V and T_{opr} = −20 to 85°C (N version) / −40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
—	Program/erase endurance (1)		10,000 (2)	—	—	times
—	Byte program time (program/erase endurance ≤ 1,000 times)		—	160	1500	µs
—	Byte program time (program/erase endurance > 1,000 times)		—	300	1500	µs
—	Block erase time (program/erase endurance ≤ 1,000 times)		—	0.2	1	s
—	Block erase time (program/erase endurance > 1,000 times)		—	0.3	1	s
$t_{d(SR-SUS)}$	Time delay from suspend request until suspend		—	—	5 + CPU clock × 3 cycles	ms
—	Interval from erase start/restart until following suspend request		0	—	—	ms
—	Time from suspend until erase restart		—	—	30+CPU clock × 1 cycle	µs
$t_{d(CMDRST-READY)}$	Time from when command is forcibly terminated until reading is enabled		—	—	30+CPU clock × 1 cycle	µs
—	Program, erase voltage		2.7	—	5.5	V
—	Read voltage		1.8	—	5.5	V
—	Program, erase temperature		−20 (6)	—	85	°C
—	Data hold time (7)	Ambient temperature = 55 °C	20	—	—	year

Notes:
1. Definition of programming/erasure endurance
   The programming and erasure endurance is defined on a per-block basis.
   If the programming and erasure endurance is n (n = 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.
   However, the same address must not be programmed more than once per erase operation (overwriting prohibited).
2. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
3. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. In addition, averaging the erasure endurance between blocks A to D can further reduce the actual erasure endurance. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.
4. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
5. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
6. −40°C for D version.
7. The data hold time includes time that the power supply is off or the clock is not supplied.

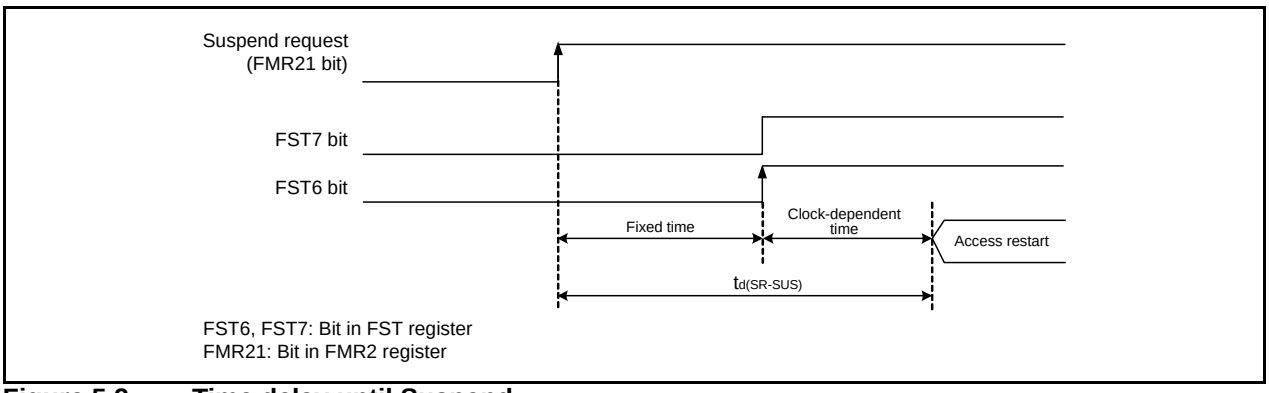


Figure 5.2 Time delay until Suspend

Table 5.19 DC Characteristics (3) [2.7 V ≤ Vcc < 4.0 V]
(Topr = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter		Condition	Standard			Unit
				Min.	Typ.	Max.	
V_{OH}	Output “H” voltage	Port P10, P11 (1)	I_{OH} = –5 mA	V_{CC} – 0.5	—	V_{CC}	V
		Other pins	I_{OH} = –1 mA	V_{CC} – 0.5	—	V_{CC}	V
		XOUT	I_{OH} = –200 μA	1.0	—	—	V
V_{OL}	Output “L” voltage	Port P10, P11 (1)	I_{OL} = 5 mA	—	—	0.5	V
		Other pins	I_{OL} = 1 mA	—	—	0.5	V
		XOUT	I_{OL} = 200 μA	—	—	0.5	V
V_{T+}-V_{T-}	Hysteresis	$\overline{INT0}$, $\overline{INT1}$, $\overline{INT2}$, $\overline{INT3}$, $\overline{INT4}$, $\overline{INT5}$, $\overline{INT6}$, $\overline{INT7}$, $\overline{KI0}$, $\overline{KI1}$, $\overline{KI2}$, $\overline{KI3}$, $\overline{KI4}$, $\overline{KI5}$, $\overline{KI6}$, $\overline{KI7}$, TRAIO, TRCIOA, TRCIOB, TRCIOC, TRCIOD, TRDIOA0, TRDIOB0, TRDIOC0, TRDIOD0, TRDIOA1, TRDIOB1, TRDIOC1, TRDIOD1, TRCTRG, TRCCLK, TRGCLKA, TRGCLKB, $\overline{TRGIOA}$, TRGIOB, $\overline{ADTRG}$, RXD0, RXD1, RXD2, CLK0, CLK1, CLK2, SSI, SCL, SDA, SSO		0.05	0.4	—	V
		$\overline{RESET}$, $\overline{WKUP0}$		0.1	0.8	—	V
I_{IH}	Input “H” current		VI = 3.0 V, V_{CC} = 3.0 V	—	—	5.0	μA
I_{IL}	Input “L” current		VI = 0 V, V_{CC} = 3.0 V	—	—	–5.0	μA
R_{PULLUP}	Pull-up resistance		VI = 0 V, V_{CC} = 3.0 V	30	100	170	kΩ
R_{fXIN}	Feedback resistance	XIN		—	0.3	—	MΩ
R_{fXCIN}	Feedback resistance	XCIN		—	14	—	MΩ
V_{RAM}	RAM hold voltage		During stop mode	1.8	—	—	V

Note:
1. This applies when the drive capacity of the output transistor is set to High by registers P10DRR and P11DRR. When the drive capacity is set to Low, the value of any other pin applies.

Table 5.21 DC Characteristics (5) [1.8 V ≤ Vcc < 2.7 V]
(Topr = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter		Condition	Standard			Unit
				Min.	Typ.	Max.	
V_{OH}	Output “H” voltage	Port P10, P11 (1)	I_{OH} = –2 mA	V_{CC} – 0.5	—	V_{CC}	V
		Other pins	I_{OH} = –1 mA	V_{CC} – 0.5	—	V_{CC}	V
		XOUT	I_{OH} = –200 μA	1.0	—	—	V
V_{OL}	Output “L” voltage	Port P10, P11 (1)	I_{OL} = 2 mA	—	—	0.5	V
		Other pins	I_{OL} = 1 mA	—	—	0.5	V
		XOUT	I_{OL} = 200 μA	—	—	0.5	V
V_{T+}-V_{T-}	Hysteresis	$\overline{INT0}$, $\overline{INT1}$, $\overline{INT2}$, $\overline{INT3}$, $\overline{INT4}$, INT5, $\overline{INT6}$, INT7, $\overline{KI0}$, $\overline{KI1}$, $\overline{KI2}$, $\overline{KI3}$, $\overline{KI4}$, $\overline{KI5}$, $\overline{KI6}$, $\overline{KI7}$, TRAIO, TRCIOA, TRCIOB, TRCIOC, TRCIOD, TRDIOA0, TRDIOB0, TRDIOC0, TRDIOD0, TRDIOA1, TRDIOB1, TRDIOC1, TRDIOD1, TRCTRG, TRCCLK, TRGCLKA, TRGCLKB, $\overline{TRGIOA}$, TRGIOB, $\overline{ADTRG}$, RXD0, RXD1, RXD2, CLK0, CLK1, CLK2, SSI, SCL, SDA, SSO		0.05	0.4	—	V
		$\overline{RESET}$, $\overline{WKUP0}$		0.1	0.8	—	V
I_{IH}	Input “H” current		VI = 1.8 V, V_{CC} = 1.8 V	—	—	4.0	μA
I_{IL}	Input “L” current		VI = 0 V, V_{CC} = 1.8 V	—	—	–4.0	μA
R_{PULLUP}	Pull-up resistance		VI = 0 V, V_{CC} = 1.8 V	60	160	420	kΩ
R_{fXIN}	Feedback resistance	XIN		—	0.3	—	MΩ
R_{fXCIN}	Feedback resistance	XCIN		—	14	—	MΩ
V_{RAM}	RAM hold voltage		During stop mode	1.8	—	—	V

Note:
1. This applies when the drive capacity of the output transistor is set to High by registers P10DRR and P11DRR. When the drive capacity is set to Low, the value of any other pin applies.

5.5 AC Characteristics

Table 5.23 Timing Requirements of Synchronous Serial Communication Unit (SSU) (V_{CC} = 1.8 to 5.5 V, V_{SS} = 0 V, and T_{opr} = −20 to 85°C (N version) / −40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter		Conditions	Standard			Unit
				Min.	Typ.	Max.	
t_{SUCYC}	SSCK clock cycle time			4	—	—	t_{CYC} (1)
t_{HI}	SSCK clock “H” width			0.4	—	0.6	t_{SUCYC}
t_{LO}	SSCK clock “L” width			0.4	—	0.6	t_{SUCYC}
t_{RISE}	SSCK clock rising time	Master		—	—	1	t_{CYC} (1)
		Slave		—	—	1	µs
t_{FALL}	SSCK clock falling time	Master		—	—	1	t_{CYC} (1)
		Slave		—	—	1	µs
t_{SU}	SSO, SSI data input setup time			100	—	—	ns
t_H	SSO, SSI data input hold time			1	—	—	t_{CYC} (1)
t_{LEAD}	$\overline{SCS}$ setup time	Slave		1t_{CYC} + 50	—	—	ns
t_{LAG}	$\overline{SCS}$ hold time	Slave		1t_{CYC} + 50	—	—	ns
t_{OD}	SSO, SSI data output delay time			—	—	1	t_{CYC} (1)
t_{SA}	SSI slave access time		2.7 V ≤ V_{CC} ≤ 5.5 V	—	—	1.5t_{CYC} + 100	ns
			1.8 V ≤ V_{CC} < 2.7 V	—	—	1.5t_{CYC} + 200	ns
t_{OR}	SSI slave out open time		2.7 V ≤ V_{CC} ≤ 5.5 V	—	—	1.5t_{CYC} + 100	ns
			1.8 V ≤ V_{CC} < 2.7 V	—	—	1.5t_{CYC} + 200	ns

Note:
1. 1t_{CYC} = 1/f1(s)

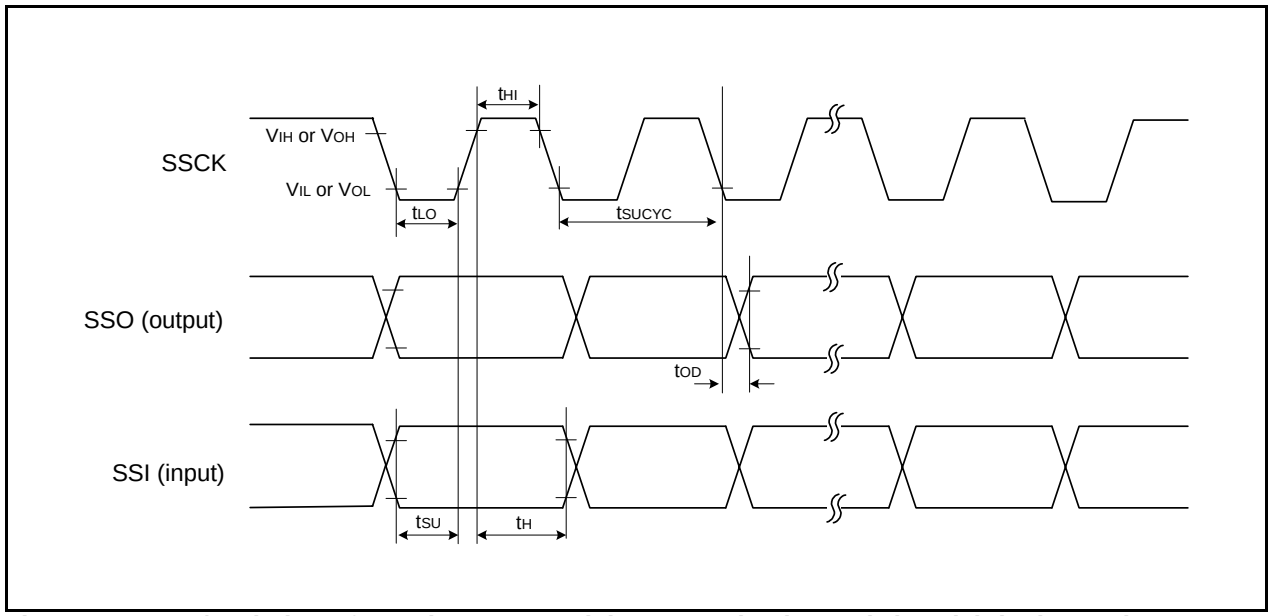


Figure 5.6 I/O Timing of Synchronous Serial Communication Unit (SSU) (Clock Synchronous Communication Mode)

Table 5.27 Timing Requirements of Serial Interface
(Vcc = 1.8 to 5.5 V, Vss = 0 V, and Topr = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Standard						Unit
		Vcc = 2.2V, Topr = 25°C		Vcc = 3V, Topr = 25°C		Vcc = 5V, Topr = 25°C		
		Min.	Max.	Min.	Max.	Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	800	—	300	—	200	—	ns
$t_{W(CKH)}$	CLKi input “H” width	400	—	150	—	100	—	ns
$t_{W(CKL)}$	CLKi input “L” width	400	—	150	—	100	—	ns
$t_{d(C-Q)}$	TXDi output delay time	—	200	—	80	—	50	ns
$t_{h(C-Q)}$	TXDi hold time	0	—	0	—	0	—	ns
$t_{su(D-C)}$	RXDi input setup time	150	—	70	—	50	—	ns
$t_{h(C-D)}$	RXDi input hold time	90	—	90	—	90	—	ns

i = 0 to 2

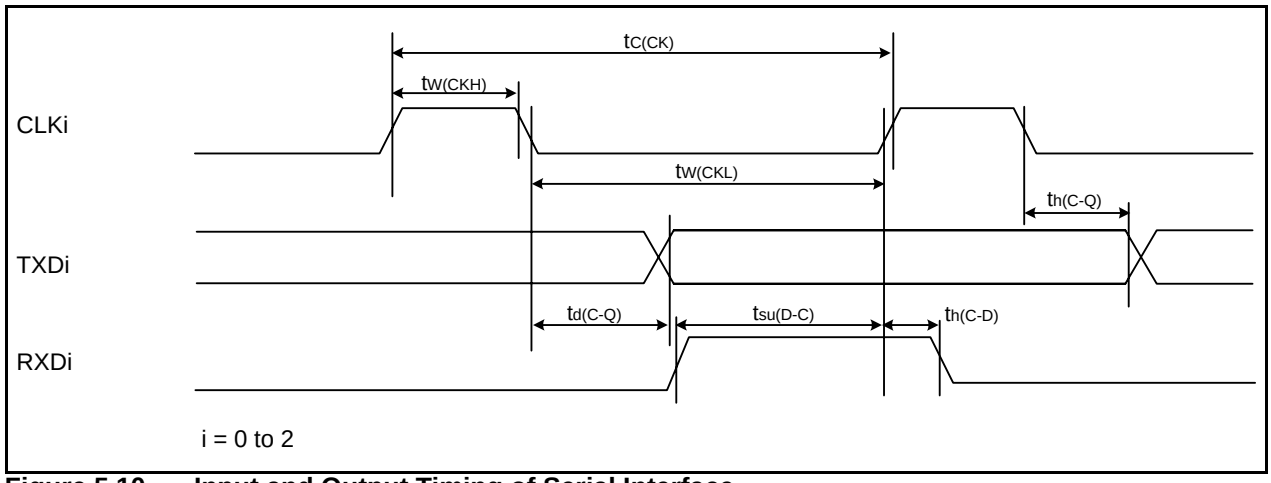


Figure 5.10 Input and Output Timing of Serial Interface

Table 5.28 Timing Requirements of External Interrupt $\overline{INTi}$ (i = 0 to 7) and Key Input Interrupt $\overline{KIi}$ (i = 0 to 7)
(Vcc = 1.8 to 5.5 V, Vss = 0 V, and Topr = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Standard						Unit
		Vcc = 2.2V, Topr = 25°C		Vcc = 3V, Topr = 25°C		Vcc = 5V, Topr = 25°C		
		Min.	Max.	Min.	Max.	Min.	Max.	
$t_{W(INH)}$	$\overline{INTi}$ input “H” width, $\overline{KIi}$ input “H” width	1000 (1)	—	380 (1)	—	250 (1)	—	ns
$t_{W(INL)}$	$\overline{INTi}$ input “L” width, $\overline{KIi}$ input “L” width	1000 (2)	—	380 (2)	—	250 (2)	—	ns

Notes:
1. When selecting the digital filter by the $\overline{INTi}$ input filter select bit, use an $\overline{INTi}$ input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
2. When selecting the digital filter by the $\overline{INTi}$ input filter select bit, use an $\overline{INTi}$ input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

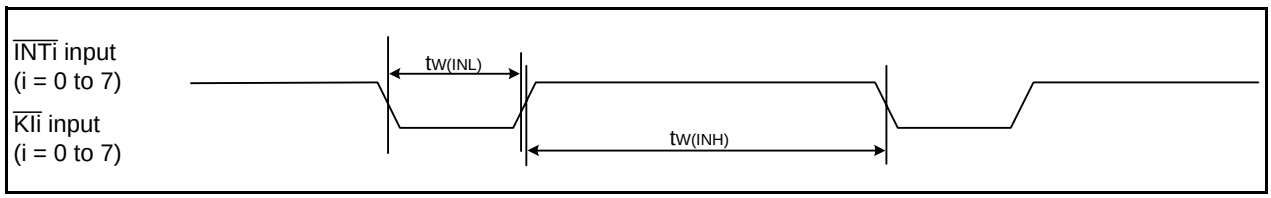
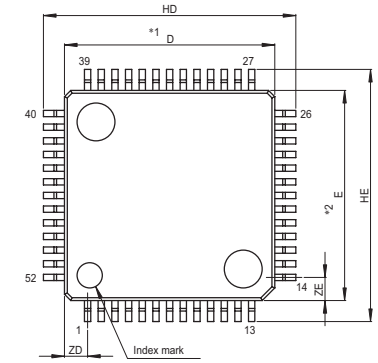


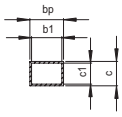
Figure 5.11 Input Timing of External Interrupt $\overline{INTi}$ and Key Input Interrupt $\overline{KIi}$

Package Dimensions

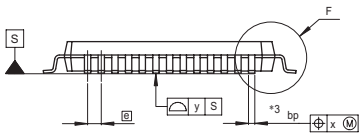
Diagrams showing the latest package dimensions and mounting information are available in the “Packages” section of the Renesas Electronics web site.

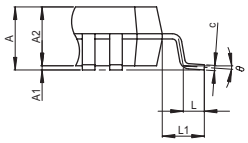
JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-LQFP52-10x10-0.65	PLQP0052JA-A	52P6A-A	0.3g





Terminal cross section



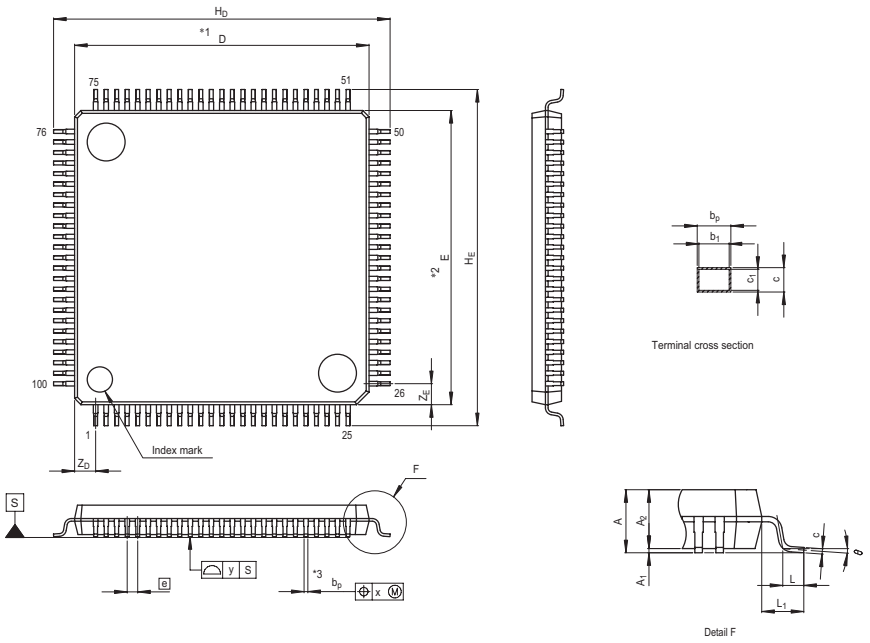


Detail F

NOTE)
1. DIMENSIONS "*1" AND "*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION "*3" DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	9.9	10.0	10.1
E	9.9	10.0	10.1
A_2	—	1.4	—
H_D	11.8	12.0	12.2
H_E	11.8	12.0	12.2
A	—	—	1.7
A_1	0.05	0.1	0.15
b_p	0.27	0.32	0.37
b_1	—	0.30	—
c	0.09	0.145	0.20
c_1	—	0.125	—
θ	0°	—	8°
e	—	0.65	—
x	—	—	0.13
y	—	—	0.10
Z_D	—	1.1	—
Z_E	—	1.1	—
L	0.35	0.5	0.65
L_1	—	1.0	—

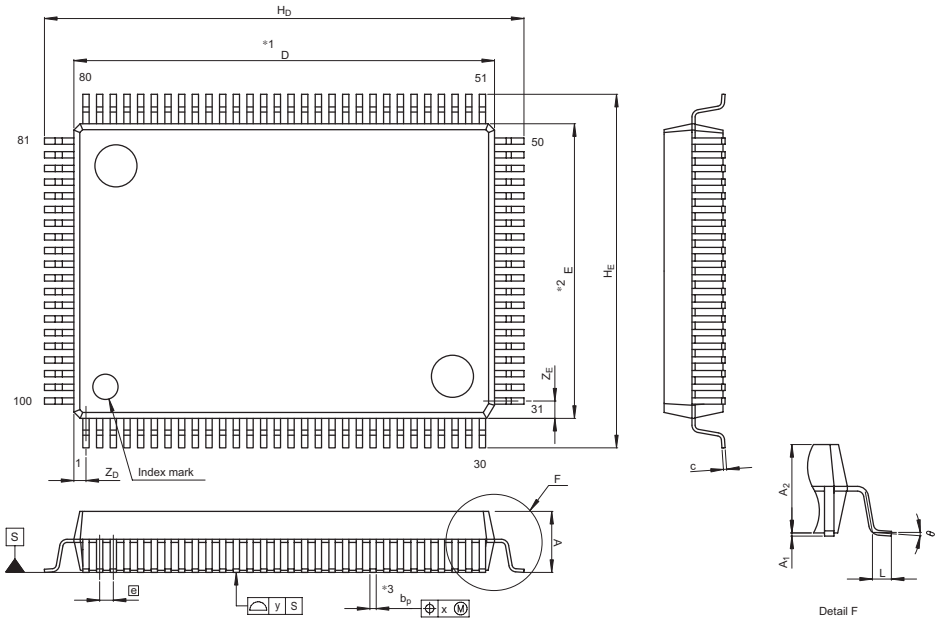
JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-LQFP100-14x14-0.50	PLQP0100KB-A	100P6Q-A / FP-100U / FP-100UV	0.6g



NOTE)
1. DIMENSIONS "*1" AND "*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION "*3" DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	13.9	14.0	14.1
E	13.9	14.0	14.1
A_2	—	1.4	—
H_D	15.8	16.0	16.2
H_E	15.8	16.0	16.2
A	—	—	1.7
A_1	0.05	0.1	0.15
b_p	0.15	0.20	0.25
b_1	—	0.18	—
c	0.09	0.145	0.20
c_1	—	0.125	—
θ	0°	—	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
Z_D	—	1.0	—
Z_E	—	1.0	—
L	0.35	0.5	0.65
L_1	—	1.0	—

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-QFP100-14x20-0.65	PRQP0100JD-B	100P6F-A	1.8g



NOTE)
1. DIMENSIONS "*1" AND "*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION "*3" DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	19.8	20.0	20.2
E	13.8	14.0	14.2
A_2	—	2.8	—
H_D	22.5	22.8	23.1
H_E	16.5	16.8	17.1
A	—	—	3.05
A_1	0	0.1	0.2
b_p	0.25	0.3	0.4
c	0.13	0.15	0.2
θ	0°	—	10°
e	—	0.65	—
x	—	—	0.13
y	—	—	0.10
Z_D	—	0.575	—
Z_E	—	0.825	—
L	0.4	0.6	0.8

REVISION HISTORY	R8C/L35C Group, R8C/L36C Group, R8C/L38C Group, R8C/L3AC Group Datasheet

Rev.	Date	Description	
		Page	Summary
0.10	Oct 30, 2009	—	First Edition issued
0.20	Apr 15, 2011	6	Table 1.6 Function deleted, Current consumption revised
		7	1.2 “of R8C/Lx Series” → “for Each Group”
		7 to 10	Tables 1.7 to 1.10 revised
		24	Table 1.15 “Voltage detection circuit” deleted
		29	4. Special Function Registers (SFRs) “The description offered in this chapter is based on the R8C/L3AC Group.” added
		45 to 68	5. Electrical Characteristics added
1.00	Jun 25, 2010	—	“Preliminary” and “Under development” deleted
		1	1.1 revised
		7 to 10	Tables 1.7 to 1.10 revised
		45	Tables 5.1 Note 2 added
		55	Table 5.15 Note 3 added
		69 to 72	Package Dimensions revised
1.01	Apr 15, 2011	2	Table 1.1 revised
		3	Table 1.2 Note 2, Table 1.3 Note 1 revised
		6	Table 1.6 “Flash Memory” revised
		11 to 14	Figure 1.5 to Figure 1.8 revised
		20 to 22	Table 1.11 to Table 1.13 “Voltage Detection Circuit” deleted
		23, 24	Table 1.14 and Table 1.15 title “for R8C/L3AC Group” added
		28	3. “The internal ROM ... with address 0FFFFh.” deleted
		38 to 40	Table 4.10 to Table 4.12 “0248h to 026Fh”, “02A8h to 02BFh”, “02C0h to 02CFh” revised
		48	Table 5.3 “t_{CONV}”, “t_{SAMP}” revised
		57, 59, 61	Table 5.18, Table 5.20, Table 5.22 “High-Speed” → “High-Speed (fOCO-F)”

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